

Ultra-Broadband Silicon Capacitor UBSC 0201 47nF BV11



Rev. 3.01

General description

UBSC Capacitor targets Optical communication system such as ROSA/TOSA, SONET and all optoelectronics as well as High speed data system or products.

The UBSC is suitable for DC blocking, feedback, coupling and bypassing applications in all broadband optoelectronics and High-speed data system.

The unique technology of integrated passive device in silicon, developed by Murata Integrated Passive Solutions, offers unique performances with low insertion loss, low reflection and phase stability from 34 KHz to 80 GHz+.

These capacitors in ultra-deep trenches in silicon have been developed in a semiconductor process, in order to integrate trench MOS capacitor providing high capacitance value of 47 nF (for kHz–MHz range) and high frequency MIM capacitors for low capacitance value for GHz range), combined in a 0201 [0.8x0.6mm] case.

The UBSC capacitor provides very high stability of the capacitance over temperature, voltage variation as well as a very high reliability.

UBSC capacitors have an extended operating temperature ranging from -55 to 150°C, with very low capacitance change over temperature.

Assembly: Suitable for surface mounted application on rigid PCB, ceramic substrate, FR4 (laminate) or flex platforms.

Bump finishing: SAC305 type 6.

Copper pads optional for embedding version and ENIG for un-bumped version, as an optional finishing.

Key features

- Ultra-Large band performance up to 80 GHz
- Resonance free
- Phase stability
- Insertion loss < 0.3dB Typ. up to 80 GHz
- Ultra-high stability of capacitance value:
 - Temperature 70ppm/K (-55 °C to +150 °C)
 - Voltage < -0.1%/Volt
 - Negligible capacitance loss through ageing
- Low profile: 400µm, 100 µm on request
- Break down voltage: 11V
- Low leakage current < 100pA
- High reliability
- High operating temperature (up to 150 °C)
- Compatible with high temperature cycling during manufacturing operations (exceeding 300 °C)
- Compatible with EIA 0201 footprint

Key applications

- ROSA/TOSA
- SONET
- High speed digital logic
- Microwave/millimetre system
- High volumetric efficiency (i.e. capacitance per unit volume)
- Broadband test equipment



Functional diagram

The next figure provides implementation set-up diagram.



Figure 1 Block Diagram

Electrical performances

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
C	Capacitance value	@+25°C	-	47	-	nF
ΔC_P	Capacitance tolerance ⁽¹⁾	@+25°C	-15	-	+15	%
T _{OP}	Operating temperature		-55	20	150	°C
T _{STG}	Storage temperature ⁽²⁾		-70	-	165	°C
ΔC_T	Capacitance temperature variation	-55 °C to 150 °C	-	70	-	ppm/K
RV _{DC}	Rated voltage ⁽³⁾		-	-	3.8 ⁽⁴⁾ 3.4 ⁽⁵⁾	V _{DC}
BV	Break down voltage	@+25°C	11	-	-	V
ΔC_{RVDC}	Capacitance voltage variation	From 0 V to RV _{DC} , @+25°C	-	-	-0.1	%/V _{DC}
IR	Insulation resistor	@RV _{DC} , +25°C, 120s	-	10	-	GΩ
ESL	Equivalent Serial Inductance	@+25°C, SRF shunt mode	-	20	-	pH
ESR	Equivalent Serial Resistance	@+25°C, shunt mode	-	220	-	mOhm
F _{c-3dB}	Cut-off frequency at 3dB	@+25°C	-	34	40	kHz
IL	Insertion loss	@ 20 GHz, +25°C	-	0.2	-	dB
		@ 40 GHz, +25°C	-	0.3	-	dB
		@ 60 GHz, +25°C	-	0.3	-	dB
		@ 80 GHz, +25°C	-	0.3	-	dB
RL	Return loss	Up to 60 GHz, +25°C	16	-	-	dB
ESD	HBM stress ⁽⁶⁾	JS-001-2017	2	-	-	kV

Table 1 - Electrical performances

⁽¹⁾: other tolerance available upon request.

⁽²⁾: without packaging.

⁽³⁾: Lifetime is voltage and temperature dependent, please refer to application note 'Lifetime of 3D capacitors'.

⁽⁴⁾: 10 years of intrinsic lifetime prediction at 100°C continuous operation.

⁽⁵⁾: 10 years of intrinsic lifetime prediction at 150°C continuous operation.

⁽⁶⁾: please refer to application note 'ESD Challenge in 3D Murata Integrated Passive technology'.



Module of S-parameters of 47nF UBSC in transmission mode

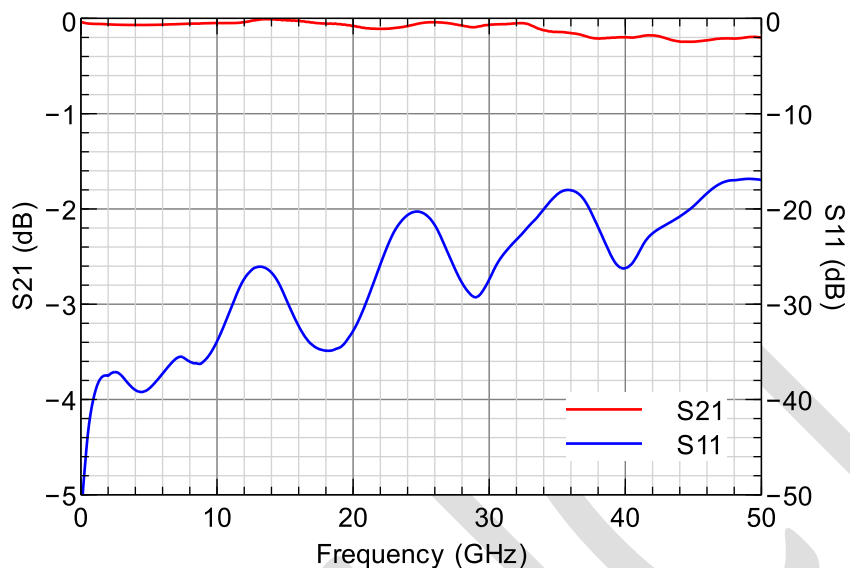
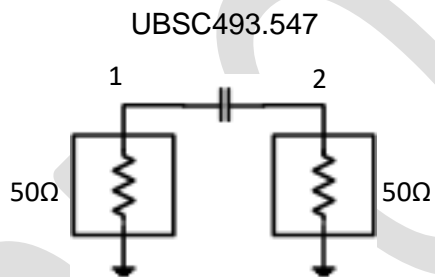


Figure 2 - 47nF UBSC Measured results (module of S-parameters)

Schematic of 47nF UBSC in transmission mode



6.6-mil Rogers 4350B.

Microstrip mode – line width = 0.400mm and gap = 0.300 mm. (nominal 50 ohm characteristic impedance).

Figure 3 - 47nF UBSC measurement schematic

Example of 0201 surface mounted

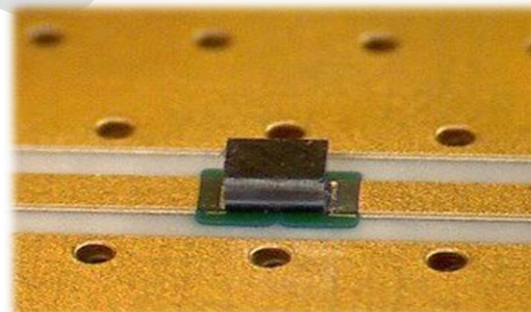


Figure 4 – micro picture of UBSC mounted on board in coplanar mode



Pinning definition

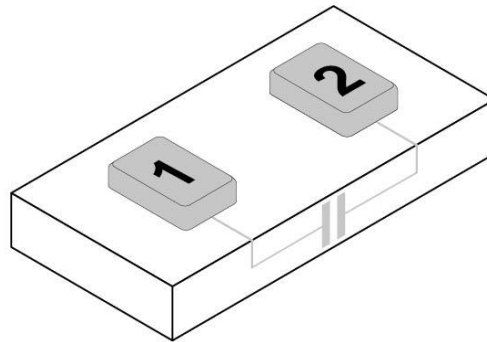


Figure 5 Pin configuration

pin #	Symbol	Coordinates X / Y
1	Signal	-225.0 / 0.0
2	Signal	225.0 / 0.0

Table 2 - Pining description. Reference (0,0) located at the centre of the die.

Ordering Information for UBSC493.547

Regardless of packaging, Murata Integrated Passive Devices delivers products with AQL level II (0.65).

Type number	Package		
	Packaging ⁽¹⁾	Finishing	Description
935151493547-T3N	7" T&R (1 000 pieces/reel) ⁽³⁾	ENIG ⁽²⁾	UBSC 0201 - 47nF – 2 pads – 0.8 x 0.6 mm x 0.40mm ⁽⁴⁾
935152493547-T3S	7" T&R (1 000 pieces/reel) ⁽³⁾	SAC ⁽²⁾	UBSC 0201 - 47nF – 2 pads – 0.8 x 0.6 mm x 0.10mm ⁽⁴⁾
935152493547-T3N	7" T&R (1 000 pieces/reel) ⁽³⁾	ENIG ⁽²⁾	UBSC 0201 - 47nF – 2 pads – 0.8 x 0.6 mm x 0.10mm ⁽⁴⁾

(1) Other film frame carrier are possible on request

(2) SAC = ENIG (0.1µm Au / 5µm Ni) + SAC305 type 6 or NiAu = ENIG (0.1µm Au / 5µm Ni)

(3) missing capacitors can reach 0.5%

(4) refer to Figure 9

Table 3 - Packaging and ordering information

Product Name	Die Name	Description
UBSC493.547	XC0201547	UBSC 47nF/0201/BV11 – 2 pads – 0.8 x 0.6 mm x 0.40mm
UBSC493.547	XC0201547	UBSC 47nF/0201/BV11 – 2 pads – 0.8 x 0.6 mm x 0.10mm

Table 4 - Die information



Pad Metallization

This surface mounted Silicon Capacitor is delivered as standard with ENIG (0.1 μ m Au / 5 μ m Ni) (Refer to Figure 6).

Other Metallization, such as SAC305 type 6 bumping (Refer to Figure 7), Copper, Thick Gold or Aluminum pads are possible on request.

Silicon dies are not sensitive to humidity, please refer to applications notes 'Assembly Notes' section 'Handling precautions and storage'.

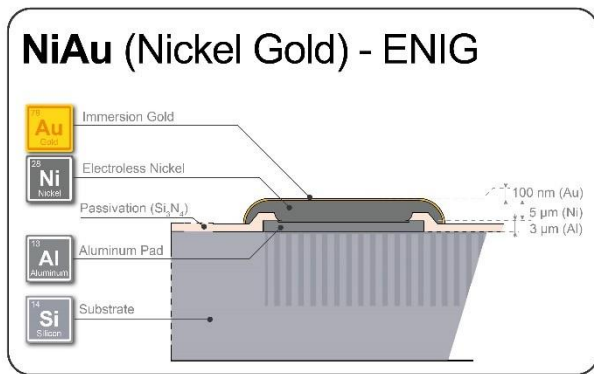


Figure 6 – Top electrode description of ENIG finishing version

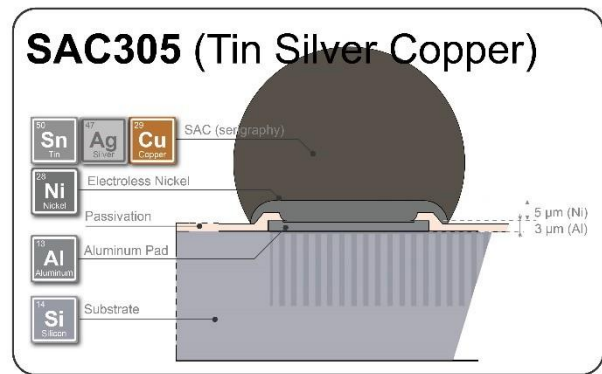


Figure 7 – Top electrode description of SAC305 pre-bumped version

Material regulation

This product is RoHS compliant at the time of publication. For further information about regulation compliancy, please ask your sales representative.



Package outline

The product is delivered as a bare silicon die.

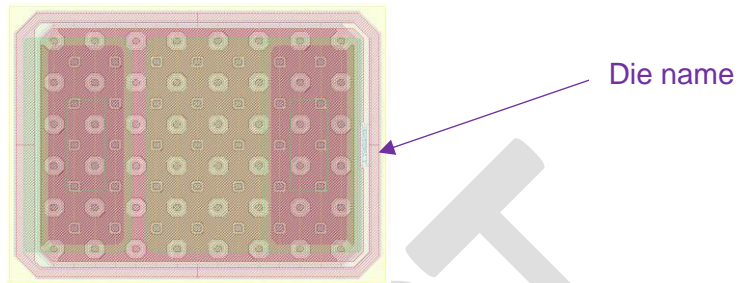


Figure 8 – Layout view

L (mm)	W (mm)	T (mm)	c (mm)	p (mm)	e (mm)	t (mm)
0.80 ±0.04	0.60 ±0.04	0.40 or 0.10 ±0.02	0.15	0.30	0.40	0.005±0.002 ⁽¹⁾ or 0.04 ⁽²⁾ 0.065 ⁽³⁾

(1) Only in case of ENIG finishing

(2) Solder joint height after reflow on board in case of SAC305 pre-bumping with mirror pads on board

(3) Solder bump height before assembly

Table 5 - Dimensions and tolerances

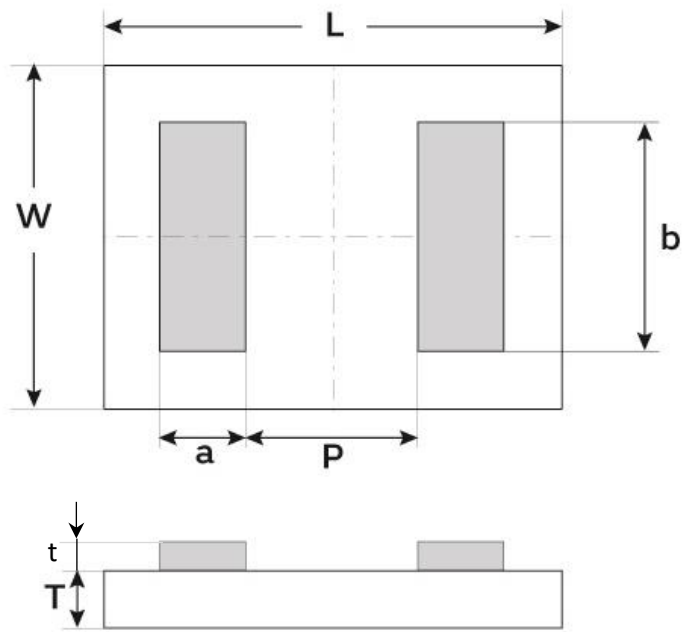


Figure 9 - Package outline drawing

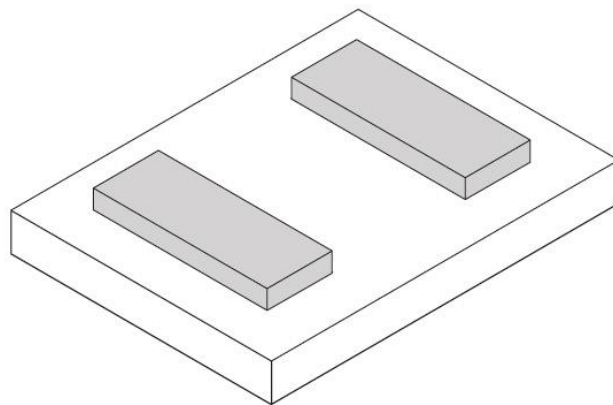


Figure 10 - Package isometric view



Assembly

UBSC series is compatible with standard reflow technology.

It is recommended to design mirror pads on the PCB.

For further information, please see our mounting application note.

The attachment techniques recommended by Murata on the customer's substrates are fully detailed in specific documents available on our website. To assure the correct use and proper functioning of Murata capacitors **please download the assembly instructions on <https://www.murata.com/en-us/products/capacitor/siliconcapacitors> and read them carefully.**



Figure 11 Scan this QR Code to access the Murata Silicon Capacitor web page



Packaging format

Please refer to application note 'Products Storage Conditions and Shelf Life'.

Tape and Reel: Dies are flipped in the tape cavity (bump down) with die ID located near the driving holes of the tape.

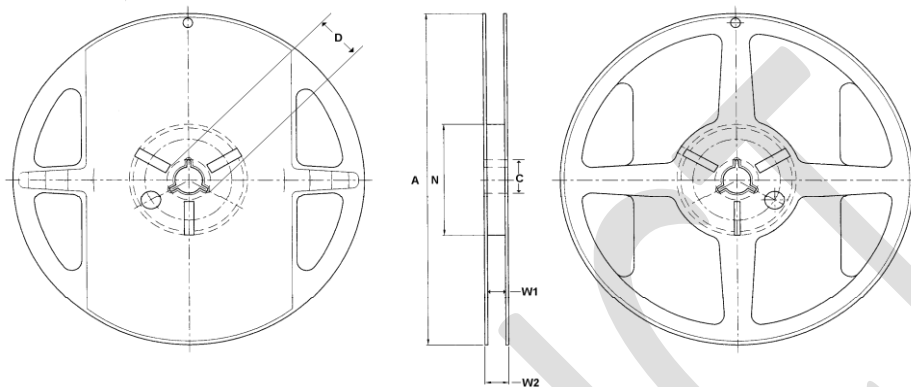


Figure 12 - Reel drawing

Tape Width	Diameter A	C	D	Hub N	W1	W2
8	178 (7 inches)	13.5	20.2	60	9.3	11.5

Table 6 - Reel dimensions (mm)

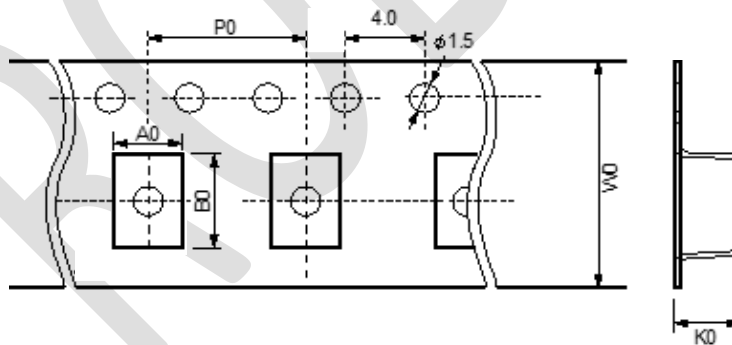


Figure 13 - Tape drawing (not to scale)

Cavity dimensions			Carrier tape width W0	Carrier tape pitch P0	Quantity per reel	Die thickness T
A0	B0	K0				
0.76	0.96	0.22	8	2	1 000	100 μ m
0.74	0.94	0.57	8	4	1 000	400 μ m

Table 7 - Tape dimensions (mm)



Definitions

Data sheet status

Objective specification: This data sheet contains target or goal specifications for product development.

Preliminary specification: This data sheet contains preliminary data; supplementary data may be published later.

Product specification: This data sheet contains final product specifications.

Limiting values

Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those given in the Electrical performances sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

Revision history

Revision	Date	Description	Author
Release 1.00	2016 Nov. 07th	Creation	OGA
Release 1.06	2021 Feb. 17th	Update	OGA
Release 2.00	2021 Apr. 07th	Preliminary release	OGA
Release 3.00	2021 July 01st	Product release	OGA
Release 3.01	2023 Dec 15th	Extended high limite frequency	DYE, OGA

Disclaimer / Life support applications

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